DECLARATION FOR PATENT APPLICATION

As a below named inventor, I declare: that I verily believe myself to be the original, first and sole (if only one individual inventor is listed below) or an original, first and joint inventor (if more than one individual inventor is listed below) of the invention in

SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE

the	specification	οf	which	is	attached	hereto	unless	the	following	box	is
chec	rked.										

was filed on	as United	States Application
or PCT International.		, and
was amended on	(if appl	icable).

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information of which is material to patentability as defined in 37 CFR 1.56.

I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or 365

I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or 365 (b) of any foreign application(s) for patent or inventor's certificate, or 35 U.S.C. 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed:

Country	Category	Application No.	Filing Date	<u>Claim</u>
Japan	Patent	2000-297703	September 28, 2000	Yes

And I hereby appoint Stuart Lubitz (Reg. No. 20,680), Louis A. Mok (Reg. No. 22,585), John P. Scherlacher (Reg. No. 23,009), William J. Kubida (Reg. No. 29,664), Stuart T. Langley (Reg. No. 33,940), Michael Byorick (Reg. No. 34,131), Carol W. Burton (Reg. No. 35,465), Steven C. Peterson (Reg. No. 36,238), William H. Wright (Reg. No. 36,312), Steven K. Barton (Reg. No. 36,445), David Lubitz (Reg. No. 38,229), Wei-Ning Yang (Reg. No. 38,690), Sarah S. O'Rourke (Reg. No. 41,226), E. Matthew G. Dyor (Reg. No. 42,278) and Ying Chen under 37 C.F.R. 10.9(b) each of whose address is Biltmore Tower, 500 South Grand Avenue, Suite 1900, Los Angeles, California 90071, or any one of them, my attorneys with full power of substitution and revocation, to prosecute this application and to transact all business in the Patent & Tradmark Office connected therewith, and request that correspondence be directed to Hogan & Hartson L.L.P., Biltmore Tower, 500 South Grand Avenue, Suite 1900, Los Angeles, California 90071. Please direct telephone calls to William H. Wright at 213-337-6700.

I declare further that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

DECLARATION FOR PATENT APPLICATION

I declare further that my mailing address is at c/o
Intellectual Property Division, KABUSHIKI KAISHA TOSHIBA, 1-1 Shibaura
1-chome, Minato-ku, Tokyo 105-8001, Japan; and
that my citizenship and residence are as stated below next to my name:

Inventor: (Signature)	Date	Residence
	Date: SEP. 19. 2001	
Katsushi Nagaba Katsushi Nagaba	Citizen of: Japan	Tokyo, Japan
	Date: SEP. 19. 2001	-
Shyddina Sige Ohshima III III III III III III III III III	Citizen of: Japan	Yokohama-shi, Japan
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	Date:	-
	Citizen of: Japan	
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	Citizen of: Japan	